

## Features

- Ideal for 802.11b/g
- +23 dBm P1dB typical at 3.3 V
- 30 dB Gain typical
- 802.11g compliant to +16.5 dBm P<sub>OUT</sub>, 3% EVM
- Micro-Amp Shutdown
- Integrated Detector
- SiGe Process: Lowest Cost Solution
- Lead-Free 2.5 X 2 mm 14-Lead PQFN Package
- Halogen-Free “Green” Mold Compound
- RoHS\* Compliant and 260°C Reflow Compatible

## Description

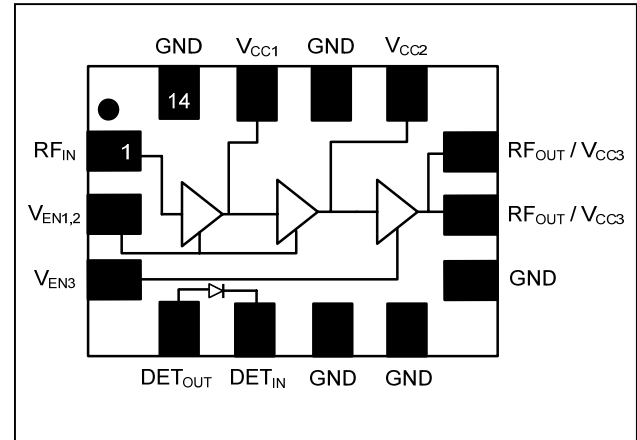
The MAAP-008516 is a three stage power amplifier, designed for WLAN applications. This power amplifier is available in a lead free 2.5 X 2 mm 14-Lead PQFN plastic package. The MAAP-008516 also features an integrated power detector, and consumes only 80 mA at -13.5 dBm input power under 802.11g modulation conditions.

## Ordering Information<sup>1,2</sup>

Part Number	Package
MAAP-008516-TR3000	3000 piece reel
MAAP-008516-001SMB	Sample Test Board

1. Reference Application Note M513 for reel size information.
2. All sample boards include 5 loose parts.

## Functional Schematic



## Pin Configuration

Pin No.	Pin Name	Description
1	RF <sub>IN</sub>	RF Input
2	V <sub>EN1,2</sub>	Power Enable
3	V <sub>EN3</sub>	Power Enable
4	DET <sub>OUT</sub>	Detector Output
5	DET <sub>IN</sub>	Detector Input
6	GND	Ground
7	GND	Ground
8	GND	Ground
9	RF <sub>OUT</sub> / V <sub>CC3</sub>	RF Output, 3rd Stage Supply
10	RF <sub>OUT</sub> / V <sub>CC3</sub>	RF Output, 3rd Stage Supply
11	V <sub>CC2</sub>	2nd Stage Supply
12	GND	Ground
13	V <sub>CC1</sub>	1st Stage Supply
14	GND	Ground
Pad	Paddle <sup>3</sup>	RF & DC Ground

3. The exposed pad centered on the package bottom must be connected to RF and DC ground.

\* Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

**Electrical Specifications: F = 2.45 GHz, V<sub>CC</sub> = 3.3 V, V<sub>EN</sub> = 2.6 V, T<sub>A</sub> = 25°C, Z<sub>0</sub> = 50 Ω**

Parameter	Test Conditions	Units	Min.	Typ.	Max.
Gain	—	dB	27.5	30	—
Input Return Loss	—	dB	—	15	—
Forward Isolation	—	dB	—	50	—
P1dB	—	dBm	—	23	—
Current	Idle	mA	—	55	95
	P <sub>IN</sub> = -13.5 dBm, Modulated <sup>4</sup>	mA	—	80	120
	P <sub>IN</sub> = -13.5 dBm, C.W.	mA	60	95	110
Off Current	V <sub>EN</sub> = 0 V	μA	—	3	20
Control Current	V <sub>EN</sub> Current	mA	—	4.5	7
Harmonics	2fo @ -13.5 dBm Input Power	dBc	—	-33	-23
	3fo @ -13.5 dBm Input Power	dBc	—	-55	-45
Duty Cycle	—	%	—	100	—
Linear Output Power	DSS source; compliance with 802.11b EVM=3.0%, OFDM, QAM-64, 54 Mbps, 802.11g	dBm	—	21.5	—
		dBm	—	16.5	—
Detector Output	P <sub>IN</sub> = -13.5 dBm, C.W.	V	—	0.65	—

4. OFDM, QAM-64, 54 Mbps

## Absolute Maximum Ratings<sup>5,6,7</sup>

Parameter	Absolute Maximum
Input Power	-5 dBm
Operating Supply Voltage	+4.0 Volts
Operating Control Voltage	+3.0 Volts
Operating Temperature	-20°C to +85°C
Junction Temperature <sup>8</sup>	+150°C
Storage Temperature	-40°C to +150°C

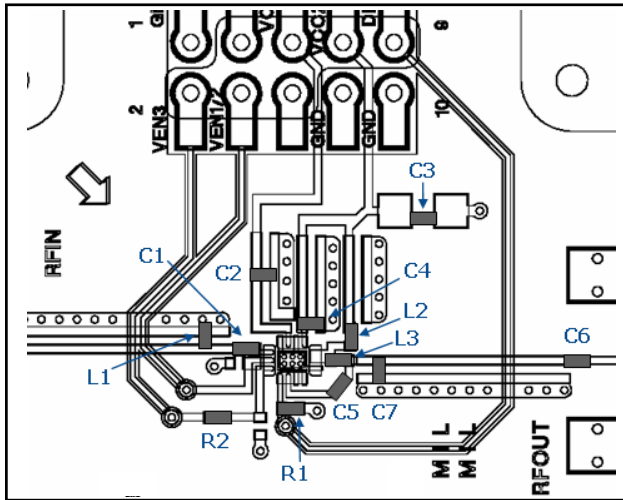
5. Exceeding any one or combination of these limits may cause permanent damage to this device.
6. M/A-COM Technology does not recommend sustained operation near these survivability limits.
7. These operating conditions will ensure MTTF > 1 x 10<sup>6</sup> hours.
8. Junction Temperature (T<sub>J</sub>) = T<sub>C</sub> + Θ<sub>JC</sub> \* ((V \* I) - (P<sub>OUT</sub> - P<sub>IN</sub>))  
Typical thermal resistance (Θ<sub>JC</sub>) = 25° C/W.
  - a) For T<sub>C</sub> = 25°C,  
T<sub>J</sub> = 31 °C @ 3.3 V, 80 mA, P<sub>OUT</sub> = 16.5 dBm, P<sub>IN</sub> = -13.5 dBm
  - b) For T<sub>C</sub> = 85°C,  
T<sub>J</sub> = 91 °C @ 3.3 V, 90 mA, P<sub>OUT</sub> = 15 dBm, P<sub>IN</sub> = -13.5 dBm

## Operating the MAAP-008516

The MAAP-008516 is static sensitive. Please handle with care. To operate the device, follow these steps.

1. Apply V<sub>CC</sub> (3.3 V).
2. Apply V<sub>EN</sub> (2.6 V).
3. Set input power.
4. Turn off in reverse order with V<sub>CC</sub> last.

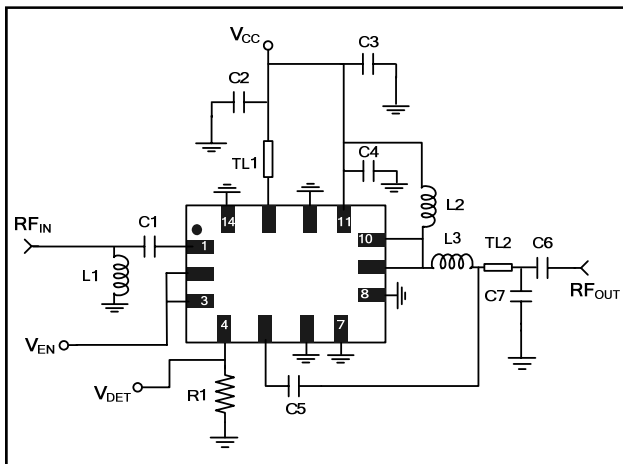
## Recommended PCB Configuration



## External Parts List

Component	Value	Footprint	Manufacturer
C1	2.7 pF	0402	Murata
C2	10 pF	0402	Murata
C3	1.0 $\mu$ F	0402	Murata
C4	0.1 $\mu$ F	0402	Murata
C5	.70 pF	0402	ATC High Q
C6	1000 pF	0402	Murata
C7	1.0 pF	0402	ATC High Q
L1	2.0 nH	0402	Coilcraft
L2	10.0 nH	0402	Coilcraft
L3	1.0 nH	0402	Coilcraft
R1	220K $\Omega$	0402	Panasonic
R2	0 $\Omega$	0402	Panasonic
TL1	50 $\Omega$ , 20.6° @ 2.45 GHz		
TL2	50 $\Omega$ , 7.4° @ 2.45 GHz		

## Evaluation Board Schematic



## Handling Procedures

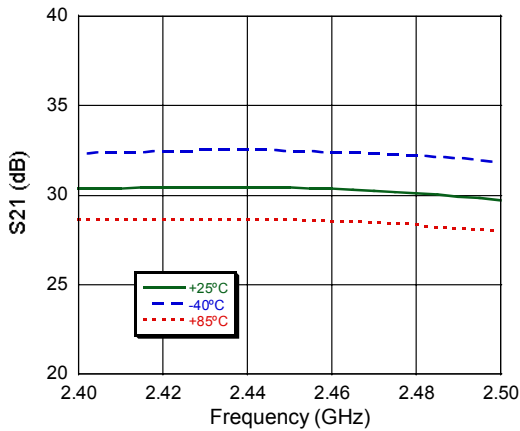
Please observe the following precautions to avoid damage:

## Static Sensitivity

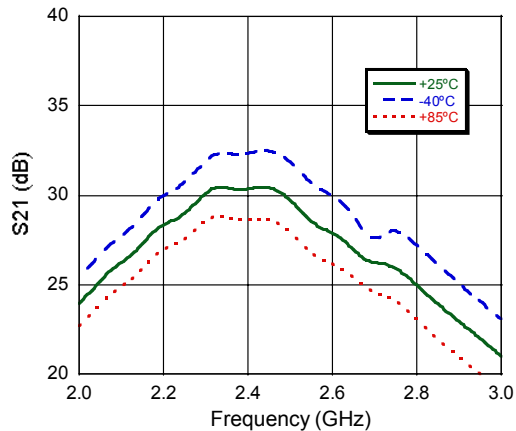
Proper ESD control techniques should be used when handling these Class 1B devices.

## Typical Performance Curves: $V_{CC} = 3.3\text{ V}$ , $V_{EN} = 2.6\text{ V}$ , over Temperature

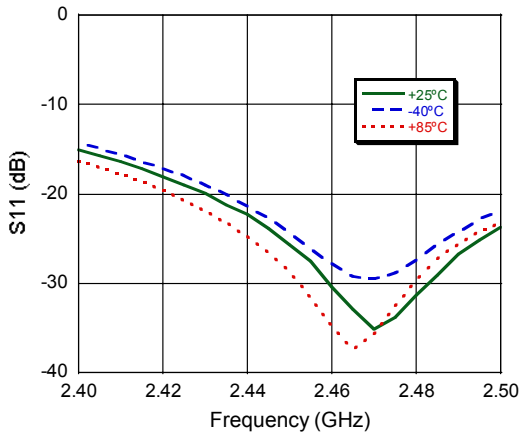
**S21 vs. Frequency (2.4 GHz - 2.5 GHz) -Gain**



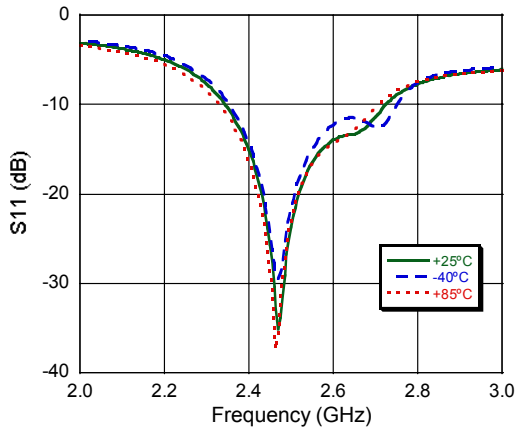
**S21 vs. Frequency -Gain**



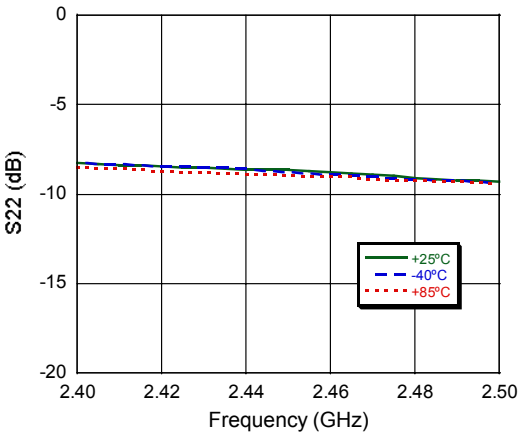
**S11 vs. Frequency (2.4 GHz - 2.5 GHz)**



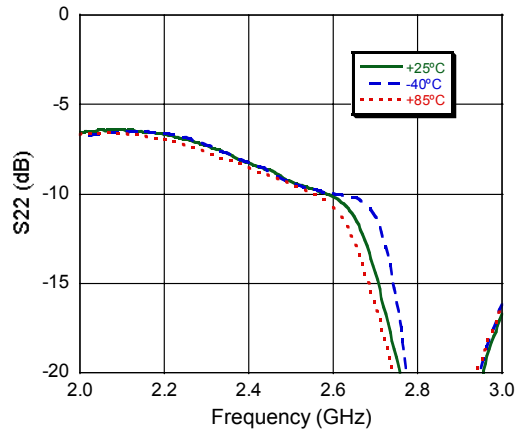
**S11 vs. Frequency**



**S22 vs. Frequency (2.4 GHz - 2.5 GHz)**

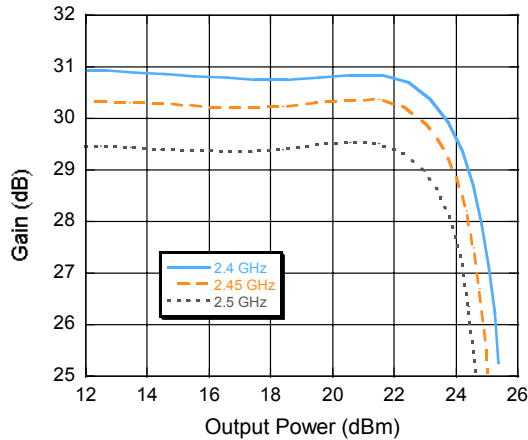


**S22 vs. Frequency**

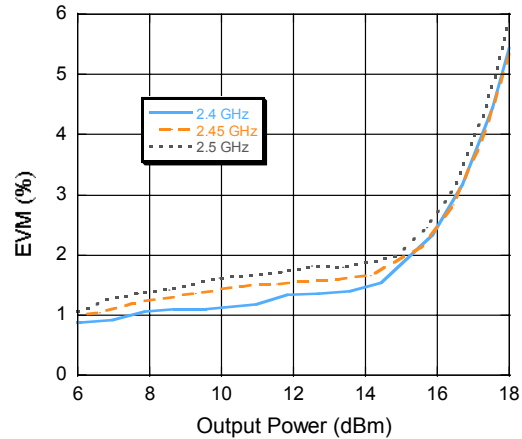


**Typical Performance Curves:  $V_{CC} = 3.3\text{ V}$ ,  $V_{EN} = 2.6\text{ V}$**

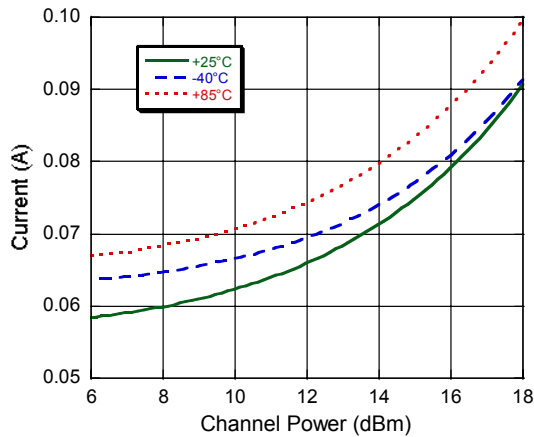
**$P_{1dB}$  @ 2.4 - 2.5 GHz**



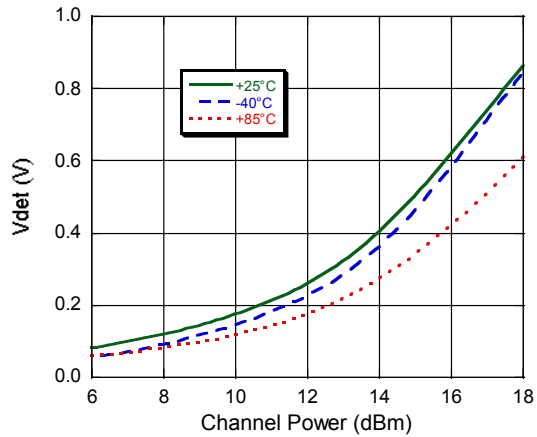
**EVM vs.  $P_{OUT}$  @ 2.4 - 2.5 GHz, OFDM, QAM-64, 54 Mbps**



**Modulated Current vs.  $P_{OUT}$  over Temperature @ 2.45 GHz**

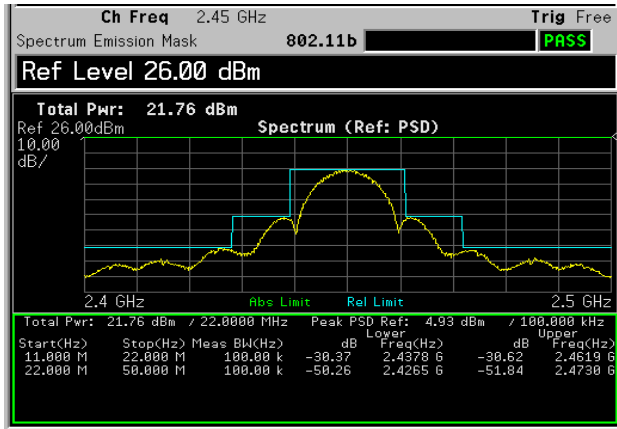


**$V_{DET}$  vs.  $P_{OUT}$  over Temperature @ 2.45 GHz**

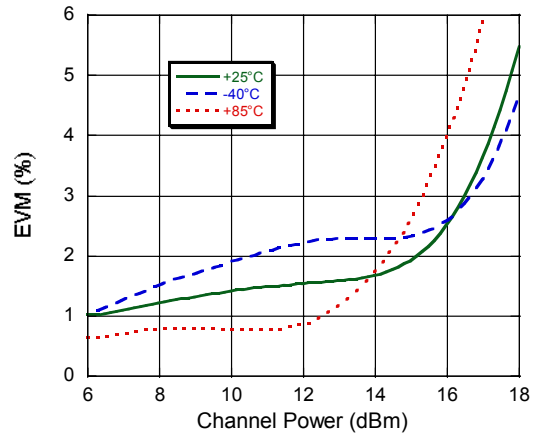


### Typical Performance Curves: $V_{CC} = 3.3\text{ V}$ , $V_{EN} = 2.6\text{ V}$

#### 802.11b Spectrum Emission Mask @ 2.45 GHz

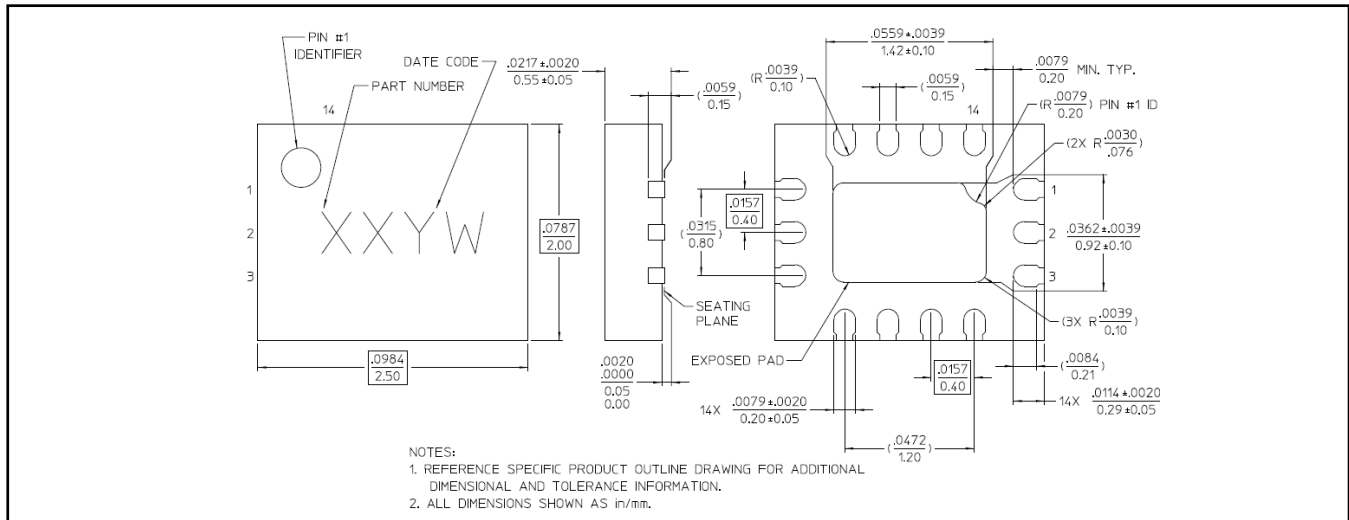


#### EVM vs. $P_{OUT}$ over Temperature @ 2.45 GHz, OFDM, QAM-64, 54 Mbps<sup>9</sup>



9. Includes system level EVM of 0.7%

### Lead-Free 2.5 x 2 mm 14-Lead PQFN†



† Reference Application Note S2083 for lead-free solder reflow recommendations.  
Meets JEDEC moisture sensitivity level 1 requirements.  
Plating is 100% matte tin over copper.